

SMT GaAs PHEMT MMIC AMP-DOUBLER-AMP, 9.0 - 16.0 GHz OUTPUT

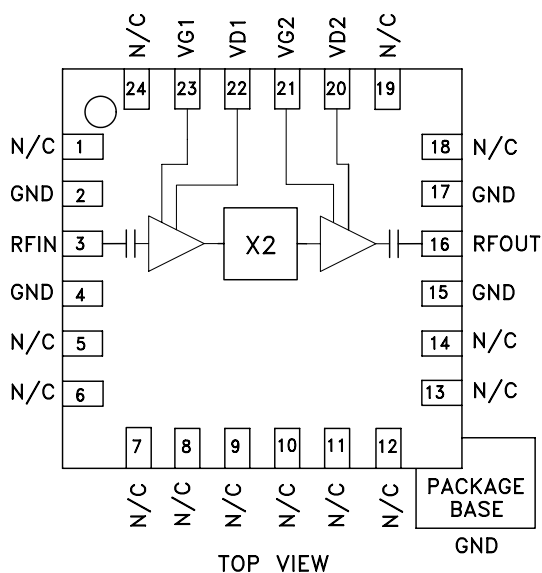
Typical Applications

- Microwave Radios & VSAT
- Fiber Optic Infrastructure
- Military Communications & Radar

Features

Output Power: +15 dBm
Wide Input Power Range: 0 to +10 dBm
100 kHz SSB Phase Noise: -140 dBc/Hz
+5V @ 75 mA Supply
16 mm² Leadless QFN SMT Package

Functional Diagram



General Description

The HMC368LP4 is a miniature amp-doubler-amp utilizing GaAs PHEMT technology in a 4 mm x 4 mm leadless surface mount package. When driven by a +2 dBm signal, the multiplier provides +15 dBm typical output power from 9 to 16 GHz. The F_o and the $3F_o$ isolations are 18 dB typical. The low additive SSB phase noise of -140 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance. The HMC368LP4 is ideal for use in LO multiplier chains allowing reduced parts count vs. traditional approaches.

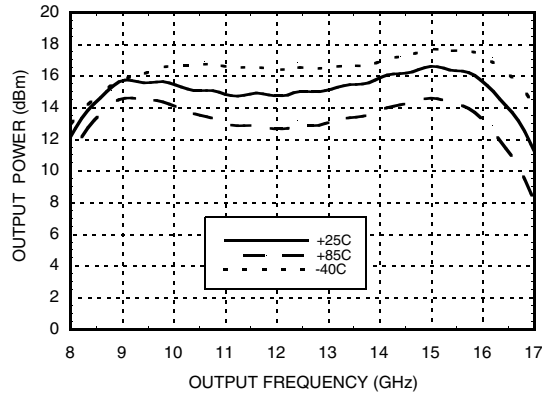
Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{d1} = V_{d2} = +5.0\text{ Vdc}$, +2 dBm Drive Level

Parameter	Min.	Typ.	Max.	Units
Frequency Range, Input		4.5 - 8.0		GHz
Frequency Range, Output		9.0 - 16.0		GHz
Output Power	12	15		dBm
F_o Isolation (with respect to output level)		18		dB
$3F_o$ Isolation (with respect to output level)		18		dB
Input Return Loss		10		dB
Output Return Loss		10		dB
SSB Phase Noise ($F_{out} = 13\text{ GHz}$, 100 kHz Offset)		-140		dBc/Hz
Supply Current (I_{dd})*		75		mA

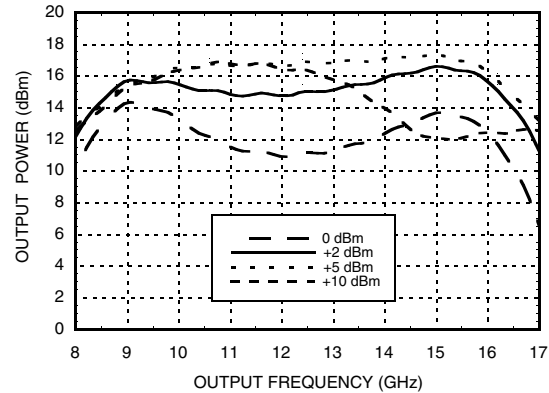
*Adjust V_{g1} , V_{g2} between -2V to 0V to achieve $I_{dd} = 75\text{ mA}$ typical

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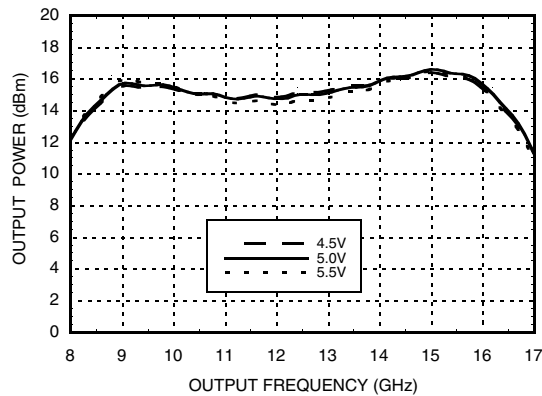
**Output Power vs.
Temperature @ +2 dBm Drive Level**



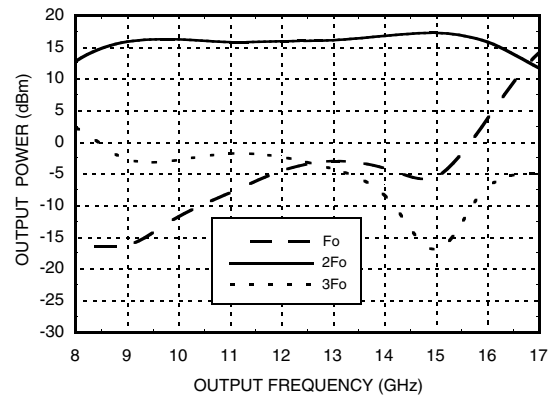
Output Power vs. Drive Level



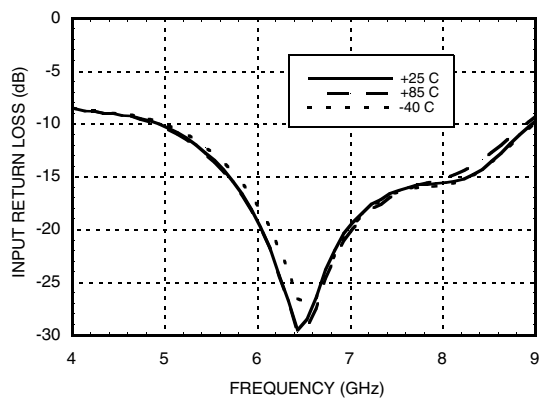
**Output Power vs.
Supply Voltage @ +2 dBm Drive Level**



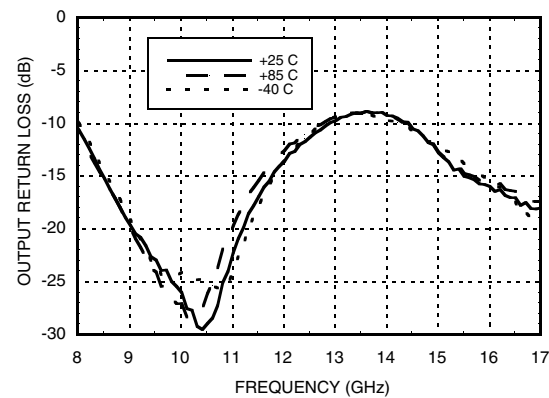
Isolation @ +2 dBm Drive Level



Input Return Loss vs. Temperature

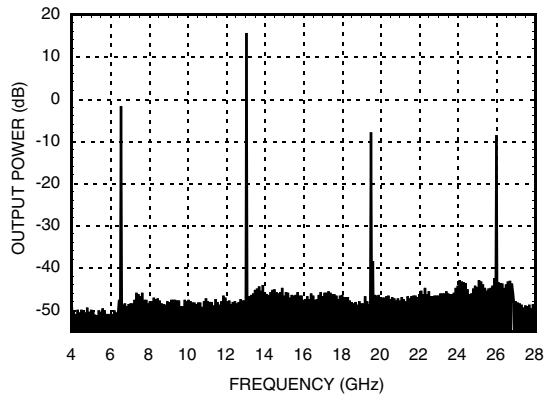


Output Return Loss vs. Temperature

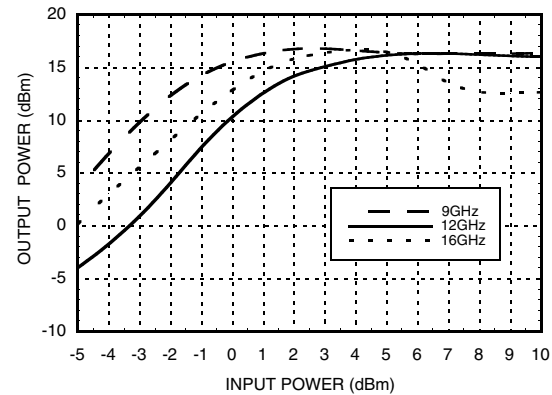


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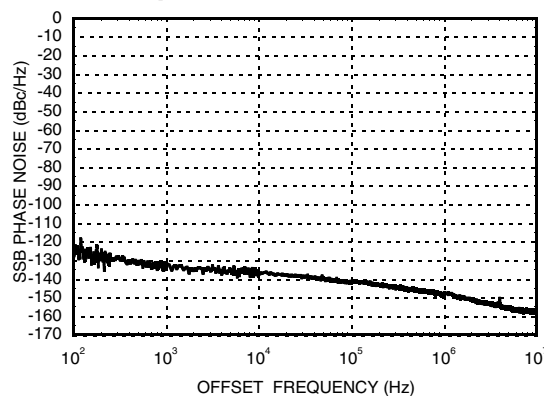
**Output Spectrum @ $F_{in} = 6.5$ GHz,
 $P_{in} = +2$ dBm**



**Output Power vs. Input Power
@ Three Frequencies**

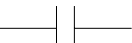
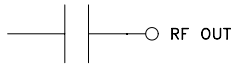
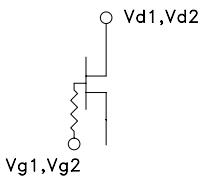


**SSB Phase Noise
Performance, $F_{out} = 13$ GHz,
Input Power = +2 dBm**



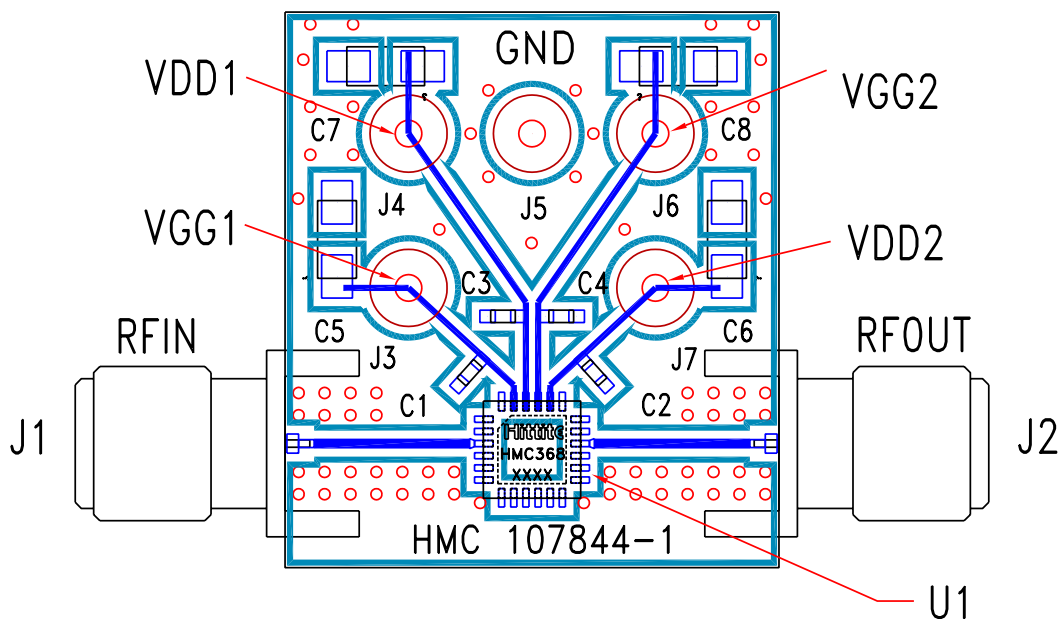
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Pin Description

Pin Number	Function	Description	Interface Schematic
1, 5-14, 18, 19, 24	N/C	No Connection. These pins may be connected to RF ground. Performance will not be affected.	
3	RF IN	Multiplier Input. AC Coupled. No external DC blocks required.	RF IN 
2, 4, 15, 17	GND	All ground leads and ground paddle must be soldered to PCB RF/DC ground.	
16	RF OUT	Multiplied Output. AC coupled. No external DC blocks necessary.	 RF OUT
20, 22	Vd2, Vd1	Drain supply voltage 5V $\pm$ 0.5V.	
21, 23	Vg2, Vg1	Gate supply voltages. Adjust between -2 Vdc to 0 Vdc to achieve 75 mA drain current.	

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Evaluation PCB



The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. The evaluation circuit board shown is available from Hittite upon request.

List of Materials for Evaluation PCB 107846*

Item	Description
J1 - J2	PC Mount SMA Connector
J3 - J7	DC Pin
C1 - C4	100 pF capacitor, 0402 Pkg.
C5 - C8	2.2 μ F capacitor, case size A
U1	HMC368LP4, Amp-x2-Amp
PCB**	107844 PCB
** Circuit Board Material: Rogers 4350	

*Reference this number when ordering complete evaluation PCB.